# **Amplifier Transistors NPN Silicon**

COLLECTOR

1

BASE

3

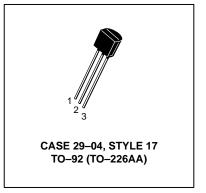
EMITTER

#### **MAXIMUM RATINGS**

Rating	Symbol	BC 546	BC 547	BC 548	Unit
Collector-Emitter Voltage	VCEO	65	45	30	Vdc
Collector-Base Voltage	V <sub>СВО</sub>	80	50	30	Vdc
Emitter-Base Voltage	VEBO	6.0			Vdc
Collector Current — Continuous	IC	100		mAdc	
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	625 5.0		mW mW/°C	
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	1.5 12		Watt mW/°C	
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150		°C	

## BC547, A, B, C BC548, A, B, C

BC546, B



#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 1.0 mA, I <sub>B</sub> = 0)	BC546 BC547 BC548	V(BR)CEO	65 45 30	_ _ _	_ _ _	V
Collector-Base Breakdown Voltage (I <sub>C</sub> = 100 μAdc)	BC546 BC547 BC548	V(BR)CBO	80 50 30	_ _ _	_ _ _	V
Emitter-Base Breakdown Voltage (I <sub>E</sub> = 10 $\mu$ A, I <sub>C</sub> = 0)	BC546 BC547 BC548	V(BR)EBO	6.0 6.0 6.0	_ _ _	_ _ _	V
Collector Cutoff Current (VCE = 70 V, VBE = 0) (VCE = 50 V, VBE = 0) (VCE = 35 V, VBE = 0) (VCE = 30 V, TA = 125°C)	BC546 BC547 BC548 BC546/547/548	ICES	_ _ _ _	0.2 0.2 0.2 —	15 15 15 4.0	nA μA

### BC546, B BC547, A, B, C BC548, A, B, C

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$  unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS		•				
DC Current Gain (I <sub>C</sub> = 10 $\mu$ A, V <sub>CE</sub> = 5.0 V)	BC547A/548A BC546B/547B/548B BC548C	hFE	_ _ _	90 150 270	_ _ _	_
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC546 BC547 BC548 BC547A/548A BC546B/547B/548B BC547C/BC548C		110 110 110 110 110 200 420		450 800 800 220 450 800	
$(I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC547A/548A BC546B/547B/548B BC548C		_ _ _	120 180 300	_ _ _	
Collector-Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.5 mA) (I <sub>C</sub> = 100 mA, I <sub>B</sub> = 5.0 mA) (I <sub>C</sub> = 10 mA, I <sub>B</sub> = See Note 1)		VCE(sat)	_ _ _	0.09 0.2 0.3	0.25 0.6 0.6	V
Base-Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.5 mA)		V <sub>BE(sat)</sub>	_	0.7	_	V
Base–Emitter On Voltage (IC = 2.0 mA, $V_{CE}$ = 5.0 V) (IC = 10 mA, $V_{CE}$ = 5.0 V)		VBE(on)	0.55 —	_ _	0.7 0.77	V
SMALL-SIGNAL CHARACTERISTICS				I.		
Current-Gain — Bandwidth Product ( $I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 100 \text{ MHz}$ )	BC546 BC547 BC548	fT	150 150 150	300 300 300	_ _ _	MHz
Output Capacitance ( $V_{CB} = 10 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz}$ )		C <sub>obo</sub>	_	1.7	4.5	pF
Input Capacitance (VEB = 0.5 V, I <sub>C</sub> = 0, f = 1.0 MHz)		C <sub>ibo</sub>	_	10	_	pF
Small–Signal Current Gain (I <sub>C</sub> = $2.0$ mA, V <sub>CE</sub> = $5.0$ V, f = $1.0$ kHz)	BC546 BC547/548 BC547A/548A BC546B/547B/548B BC547C/548C	h <sub>fe</sub>	125 125 125 125 240 450		500 900 260 500 900	_
Noise Figure (I <sub>C</sub> = 0.2 mA, V <sub>CE</sub> = 5.0 V, R <sub>S</sub> = 2 k $\Omega$ , f = 1.0 kHz, $\Delta$ f = 200 Hz)	BC546 BC547 BC548	NF	_ _ _	2.0 2.0 2.0	10 10 10	dB

Note 1:  $I_B$  is value for which  $I_C$  = 11 mA at  $V_{CE}$  = 1.0 V.

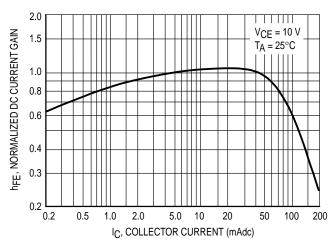


Figure 1. Normalized DC Current Gain

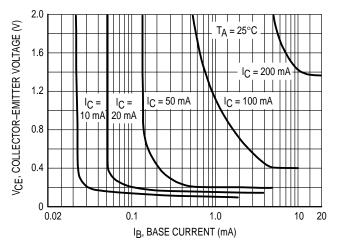


Figure 3. Collector Saturation Region

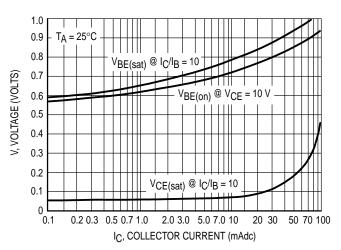


Figure 2. "Saturation" and "On" Voltages

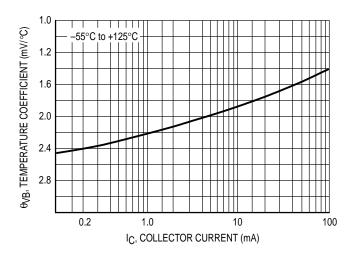


Figure 4. Base–Emitter Temperature Coefficient

#### BC547/BC548

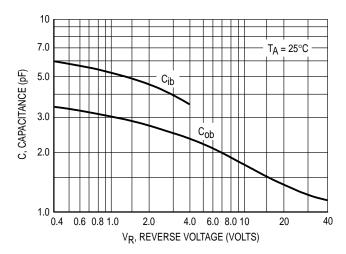


Figure 5. Capacitances

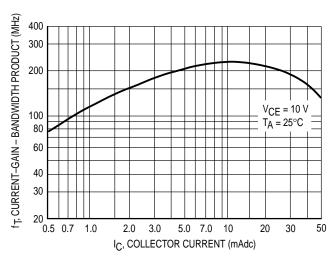


Figure 6. Current-Gain - Bandwidth Product

#### BC547/BC548

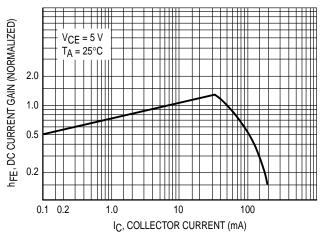


Figure 7. DC Current Gain

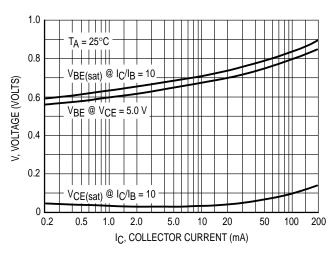


Figure 8. "On" Voltage

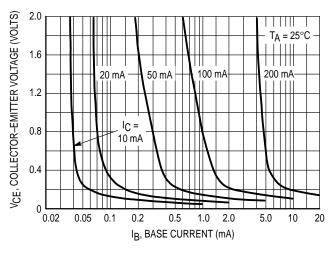


Figure 9. Collector Saturation Region

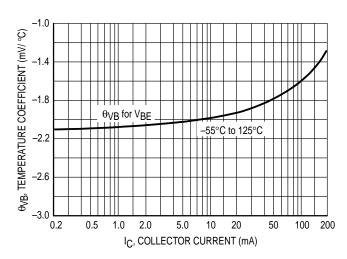


Figure 10. Base-Emitter Temperature Coefficient

#### BC546

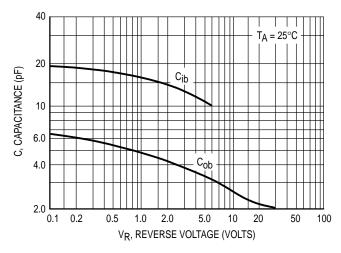


Figure 11. Capacitance

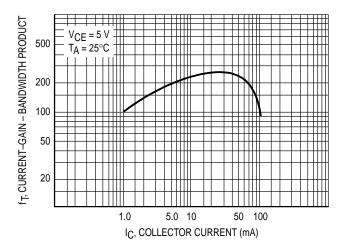
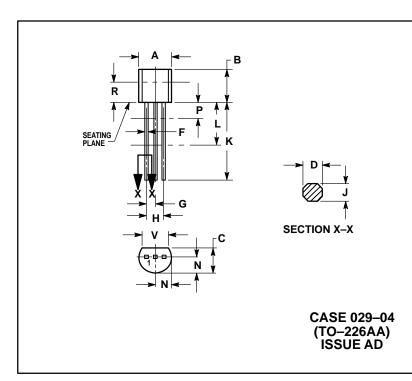


Figure 12. Current-Gain - Bandwidth Product

#### **PACKAGE DIMENSIONS**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
ν	0.135		3 43	

STYLE 17:
PIN 1. COLLECTOR
2. BASE
3. EMITTER

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